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Docket No.: 50088-057

PATENT**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

CERTIFICATION OF FACSIMILE TRANSMISSION

In re Application of

Masami SHIROSAKI, et al.

Serial No.: 09/833,734

Filed: April 13, 2001

For: SEMICONDUCTOR DEVICE AND METHOD FOR PRODUCING A
SEMICONDUCTOR DEVICE

Group Art Unit: 2811

Examiner: Not yet assigned

I HEREBY CERTIFY THAT THIS PAPER IS BEING
FACSIMILE TRANSMITTED TO THE PATENT AND
TRADEMARK OFFICE ON THE DATE SHOWN BELOW.Bonnie L. Patrick
TYPE OR PRINT NAME OF PERSON SIGNING CERTIFICATION
SIGNATURE DATE 11-5-01FAX COPY RECEIVED
NOV 5 2001**SUPPLEMENTAL PRELIMINARY AMENDMENT**

TECHNOLOGY CENTER 2800

Commissioner for Patents
Washington, DC 20231Attn: Ms. Doris King - 703-308-7722

Sir:

Prior to examination of the Preliminary Amendment filed in connection with the captioned application on April 13, 2001, please accept this Supplemental Preliminary Amendment, which conforms to the new U.S. Patent and Trademark Office requirements, in its place thereof.

IN THE SPECIFICATION:

Please amend the paragraph beginning at line 7 on page 1, as follows:

01 The present invention relates to a semiconductor device having a capacitor constituting a dynamic random access memory (DRAM) cell wherein the capacity of the capacitor is increased by roughening a surface of the cylindrical [toragse] storage node, and a method for producing such semiconductor device.